



**THE DATASHEET OF  
MC74LVX574DTG**



# MC74LVX574

## Octal D-Type Flip-Flop with 3-State Outputs

The MC74LVX574 is an advanced high speed CMOS octal flip-flop with 3-state outputs. The inputs tolerate voltages up to 7.0 V, allowing the interface of 5.0 V systems to 3.0 V systems.

This 8-bit D-type flip-flop is controlled by a clock pulse input and an output enable input. When the output enable input is high, the eight outputs are in a high impedance state.

### Features

- High Speed:  $t_{PD} = 8.5 \text{ ns}$  (Typ) at  $V_{CC} = 3.3 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 4 \mu\text{A}$  (Max) at  $T_A = 25^\circ\text{C}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Low Noise:  $V_{OLP} = 0.8 \text{ V}$  (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance:
  - Human Body Model > 2000 V;
  - Machine Model > 200 V
- These Devices are Pb-Free and are RoHS Compliant

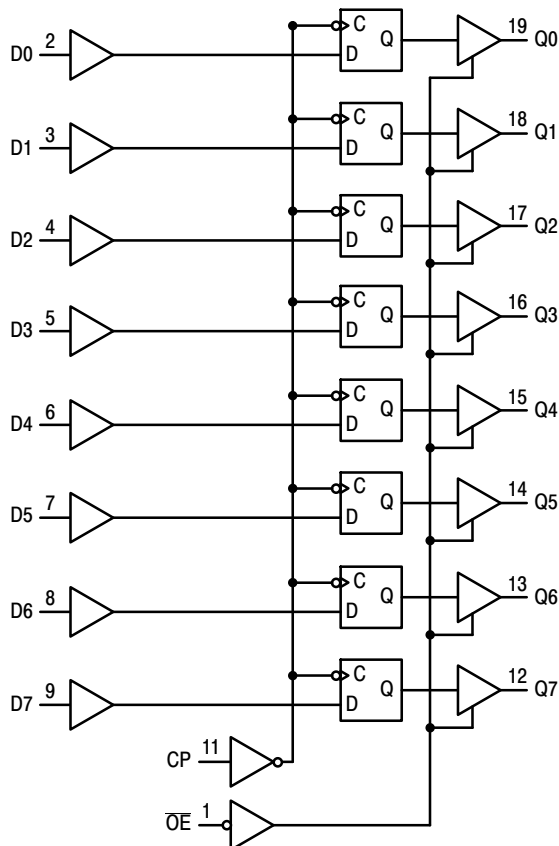
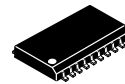


Figure 1. Logic Diagram



ON Semiconductor®

<http://onsemi.com>

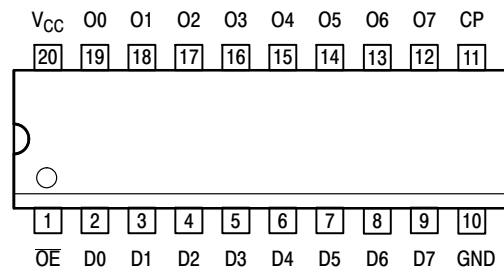


SOIC-20  
DW SUFFIX  
CASE 751D



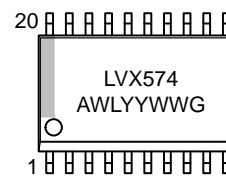
TSSOP-20  
DT SUFFIX  
CASE 948E

### PIN ASSIGNMENT

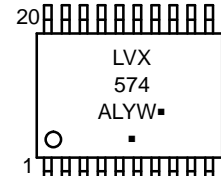


20-Lead (Top View)

### MARKING DIAGRAMS



SOIC-20



TSSOP-20

LVX574 = Specific Device Code  
A = Assembly Location  
WL, L = Wafer Lot  
Y = Year  
WW, W = Work Week  
G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION




See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# MC74LVX574

## PIN NAMES

Pins	Function
$\overline{OE}$	Output Enable Input
CP	Clock Pulse Input
D0–D7	Data Inputs
O0–O7	3–State Latch Outputs

## FUNCTION TABLE

INPUTS			OUTPUT
$\overline{OE}$	CP	D	Q
L		H	H
L		L	L
L	L, H, 	X	No Change
H	X	X	Z

## MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	DC Supply Voltage	–0.5 to +7.0	V
$V_{in}$	DC Input Voltage	–0.5 to +7.0	V
$V_{out}$	DC Output Voltage	–0.5 to $V_{CC} + 0.5$	V
$I_{IK}$	Input Diode Current	–20	mA
$I_{OK}$	Output Diode Current	±20	mA
$I_{out}$	DC Output Current, per Pin	±25	mA
$I_{CC}$	DC Supply Current, $V_{CC}$ and GND Pins	±75	mA
$P_D$	Power Dissipation	180	mW
$T_{stg}$	Storage Temperature	–65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
$V_{CC}$	DC Supply Voltage	2.0	3.6	V
$V_{in}$	DC Input Voltage	0	5.5	V
$V_{out}$	DC Output Voltage	0	$V_{CC}$	V
$T_A$	Operating Temperature, All Package Types	–40	+85	°C
$\Delta t/\Delta V$	Input Rise and Fall Time	0	100	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# MC74LVX574

## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40 to 85°C		Unit
				Min	Typ	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage		2.0 3.0 3.6	1.5 2.0 2.4			1.5 2.0 2.4		V
V <sub>IL</sub>	Low-Level Input Voltage		2.0 3.0 3.6			0.5 0.8 0.8		0.5 0.8 0.8	V
V <sub>OH</sub>	High-Level Output Voltage (V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub> )	I <sub>OH</sub> = -50 μA I <sub>OH</sub> = -50 μA I <sub>OH</sub> = -4 mA	2.0 3.0 3.0	1.9 2.9 2.58	2.0 3.0		1.9 2.9 2.48		V
V <sub>OL</sub>	Low-Level Output Voltage (V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub> )	I <sub>OL</sub> = 50 μA I <sub>OL</sub> = 50 μA I <sub>OL</sub> = 4 mA	2.0 3.0 3.0		0.0 0.0	0.1 0.1 0.36		0.1 0.1 0.44	V
I <sub>in</sub>	Input Leakage Current	V <sub>in</sub> = 5.5 V or GND	3.6			±0.1		±1.0	μA
I <sub>OZ</sub>	Maximum 3-State Leakage Current	V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub> V <sub>out</sub> = V <sub>CC</sub> or GND	3.6			±0.2 5		±2.5	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>in</sub> = V <sub>CC</sub> or GND	3.6			4.0		40.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## AC ELECTRICAL CHARACTERISTICS (Input t<sub>r</sub> = t<sub>f</sub> = 3.0ns)

Symbol	Parameter	Test Conditions	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40 to 85°C		Unit
			Min	Typ	Max	Min	Max	
f <sub>max</sub>	Maximum Clock Frequency (50% Duty Cycle)	V <sub>CC</sub> = 2.7 V C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF	60 45	115 60		50 40		ns
		V <sub>CC</sub> = 3.3 ± 0.3 V C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF	80 50	125 75		65 45		
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay CP to O	V <sub>CC</sub> = 2.7 V C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF		9.2 11.5	14.5 18.0	1.0 1.0	17.5 21.0	ns
		V <sub>CC</sub> = 3.3 ± 0.3 V C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF		8.5 11.0	13.2 16.7	1.0 1.0	15.5 19.0	
t <sub>PZL</sub> , t <sub>PZH</sub>	Output Enable Time OE to O	V <sub>CC</sub> = 2.7 V R <sub>L</sub> = 1 kΩ C <sub>L</sub> = 50 pF		9.8 11.4	15.0 18.5	1.0 1.0	18.5 22.0	ns
		V <sub>CC</sub> = 3.3 ± 0.3 V R <sub>L</sub> = 1 kΩ C <sub>L</sub> = 50 pF		8.2 10.7	12.8 16.3	1.0 1.0	15.0 18.5	
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Output Disable Time OE to O	V <sub>CC</sub> = 2.7 V R <sub>L</sub> = 1 kΩ C <sub>L</sub> = 50 pF		12.1	19.1	1.0	22.0	ns
		V <sub>CC</sub> = 3.3 ± 0.3 V R <sub>L</sub> = 1 kΩ C <sub>L</sub> = 50 pF		11.0	15.0	1.0	17.0	
t <sub>OSSL</sub> , t <sub>OSLH</sub>	Output-to-Output Skew (Note 1)	V <sub>CC</sub> = 2.7 V V <sub>CC</sub> = 3.3 ± 0.3 V C <sub>L</sub> = 50 pF C <sub>L</sub> = 50 pF			1.5 1.5		1.5 1.5	ns

- Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSSL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.

# MC74LV574

## CAPACITIVE CHARACTERISTICS

Symbol	Parameter	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40 to 85°C		Unit
		Min	Typ	Max	Min	Max	
C <sub>in</sub>	Input Capacitance		4	10		10	pF
C <sub>out</sub>	Maximum Three-State Output Capacitance		6				pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 2)		28				pF

2. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>/8 (per latch). C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

## NOISE CHARACTERISTICS (Input t<sub>r</sub> = t<sub>f</sub> = 3.0ns, C<sub>L</sub> = 50pF, V<sub>CC</sub> = 3.3V, Measured in SOIC Package)

Symbol	Characteristic	T <sub>A</sub> = 25°C		Unit
		Typ	Max	
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	0.5	0.8	V
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	-0.5	-0.8	V
V <sub>IHD</sub>	Minimum High Level Dynamic Input Voltage		2.0	V
V <sub>ILD</sub>	Maximum Low Level Dynamic Input Voltage		0.8	V

## TIMING REQUIREMENTS (Input t<sub>r</sub> = t<sub>f</sub> = 3.0ns)

Symbol	Parameter	Test Conditions	T <sub>A</sub> = 25°C		T <sub>A</sub> = -40 to 85°C		Unit
			Typ	Limit	Limit		
t <sub>w(h)</sub>	Minimum Pulse Width, CP	V <sub>CC</sub> = 2.7 V V <sub>CC</sub> = 3.3 ± 0.3 V		6.5 5.0	7.5 5.0		ns
t <sub>su</sub>	Minimum Setup Time, D to CP	V <sub>CC</sub> = 2.7 V V <sub>CC</sub> = 3.3 ± 0.3 V		5.0 3.5	5.0 3.5		ns
t <sub>h</sub>	Minimum Hold Time, D to CP	V <sub>CC</sub> = 2.7 V V <sub>CC</sub> = 3.3 ± 0.3 V		1.5 1.5	1.5 1.5		ns

## SWITCHING WAVEFORMS

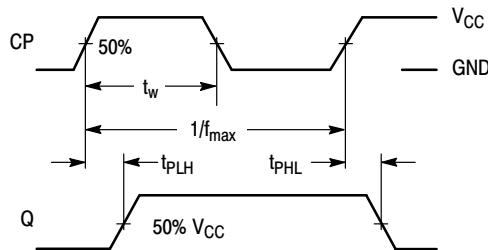


Figure 2.

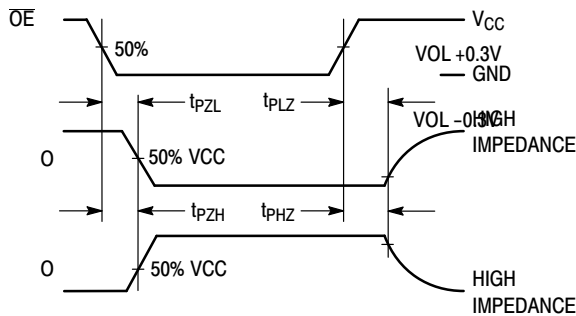


Figure 3.

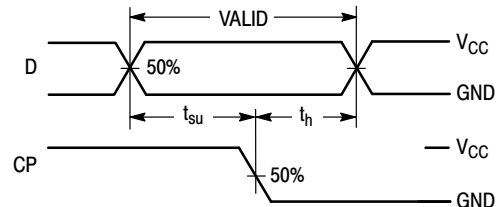
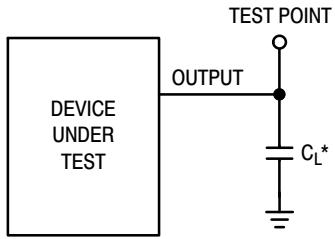


Figure 4.

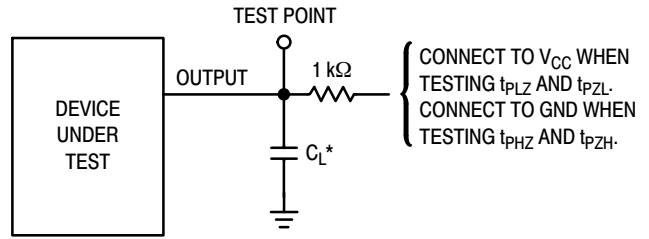
# MC74LVX574

## TEST CIRCUITS



\*Includes all probe and jig capacitance

Figure 5. Propagation Delay Test Circuit



\*Includes all probe and jig capacitance

Figure 6. Three-State Test Circuit

### ORDERING INFORMATION

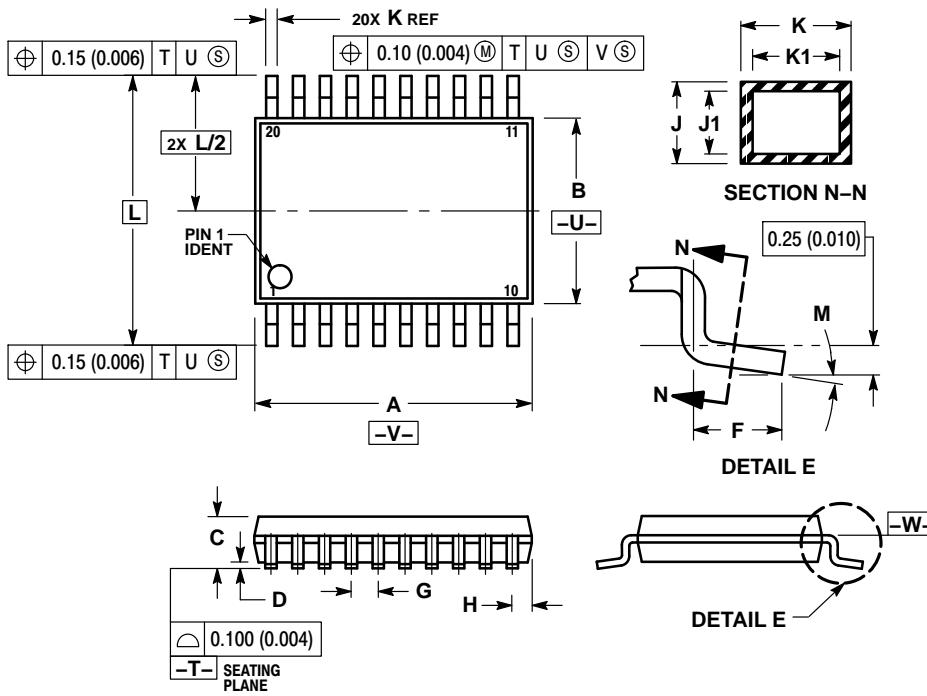
Device	Package	Shipping†
MC74LVX574DWR2G	SOIC-20 (Pb-Free)	1000 Tape & Reel
MC74LVX574DTG	TSSOP-20 (Pb-Free)	75 Units / Rail
MC74LVX574DTR2G	TSSOP-20 (Pb-Free)	2500 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MC74LVX574

## PACKAGE DIMENSIONS

TSSOP-20  
CASE 948E-02  
ISSUE C

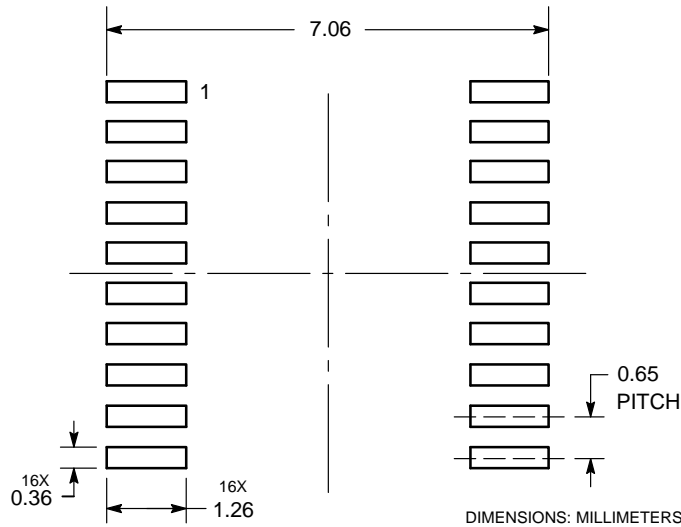


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	6.40	6.60	0.252	0.260
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

### SOLDERING FOOTPRINT\*

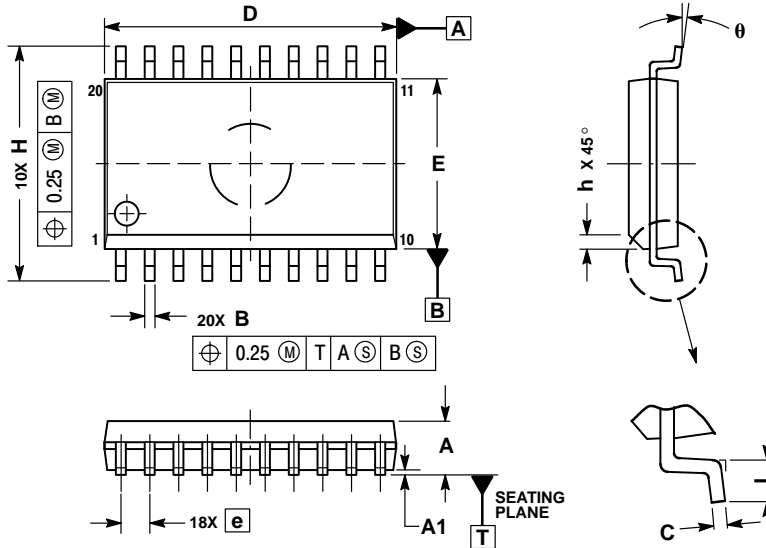


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MC74LVX574

## PACKAGE DIMENSIONS


SOIC-20  
CASE 751D-05  
ISSUE G



### NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
B	0.35	0.49
C	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

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